TOSHIBA Transistor  Silicon NPN Triple Diffused Type (PCT process)

2SC5353

Switching Regulator and High Voltage Switching Applications

High-Speed DC-DC Converter Applications

- Excellent switching times: $t_r = 0.7 \mu s$ (max), $t_f = 0.5 \mu s$ (max)
- High collectors breakdown voltage: $V_{CEO} = 800 \text{ V}$

Maximum Ratings ($T_c = 25^\circ\text{C}$)

<table>
<thead>
<tr>
<th>Characteristics</th>
<th>Symbol</th>
<th>Rating</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Collector-base voltage</td>
<td>$V_{CBO}$</td>
<td>900</td>
<td>V</td>
</tr>
<tr>
<td>Collector-emitter voltage</td>
<td>$V_{CEO}$</td>
<td>800</td>
<td>V</td>
</tr>
<tr>
<td>Emitter-base voltage</td>
<td>$V_{EBO}$</td>
<td>7</td>
<td>V</td>
</tr>
<tr>
<td>Collector current</td>
<td>$I_C$</td>
<td>3</td>
<td>A</td>
</tr>
<tr>
<td></td>
<td>$I_{CP}$</td>
<td>5</td>
<td>A</td>
</tr>
<tr>
<td>Base current</td>
<td>$I_B$</td>
<td>1</td>
<td>A</td>
</tr>
</tbody>
</table>
| Collector power dissipation | $P_C$ | 2.0    | W    | $T_a = 25^\circ\text{C}$
|                         | $P_C$  | 25     | W    | $T_c = 25^\circ\text{C}$
| Junction temperature     | $T_J$   | 150    | °C   |
| Storage temperature range| $T_{stg}$ | $-55$ to $150$ | °C   |

Maximum Ratings (Tc = 25°C)

- Collector-base voltage: $V_{CBO} = 900 \text{ V}$
- Collector-emitter voltage: $V_{CEO} = 800 \text{ V}$
- Emitter-base voltage: $V_{EBO} = 7 \text{ V}$
- Collector current: $I_C = 3 \text{ A}$, $I_{CP} = 5 \text{ A}$
- Base current: $I_B = 1 \text{ A}$
- Collector power dissipation: $P_C = 2.0 \text{ W}$, $P_C = 25 \text{ W}$
- Junction temperature: $T_J = 150 \text{ °C}$
- Storage temperature range: $T_{stg} = -55$ to $150 \text{ °C}$

Unit: mm

JEDEC  —
JEITA  SC-67
TOSHIBA  2-10R1A

Weight: 1.7 g (typ.)
## Electrical Characteristics (Tc = 25°C)

<table>
<thead>
<tr>
<th>Characteristics</th>
<th>Symbol</th>
<th>Test Condition</th>
<th>Min</th>
<th>Typ.</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Collector cut-off current</td>
<td>( I_{CBO} )</td>
<td>( V_{CB} = 720 \text{ V}, I_E = 0 )</td>
<td>—</td>
<td>—</td>
<td>100</td>
<td>( \mu \text{A} )</td>
</tr>
<tr>
<td>Emitter cut-off current</td>
<td>( I_{EBO} )</td>
<td>( V_{EB} = 7 \text{ V}, I_C = 0 )</td>
<td>—</td>
<td>—</td>
<td>10</td>
<td>( \mu \text{A} )</td>
</tr>
<tr>
<td>Collector-base breakdown voltage</td>
<td>( V_{(BR)\ CBO} )</td>
<td>( I_C = 1 \text{ mA}, I_E = 0 )</td>
<td>900</td>
<td>—</td>
<td>—</td>
<td>V</td>
</tr>
<tr>
<td>Collector-emitter breakdown voltage</td>
<td>( V_{(BR)\ CEO} )</td>
<td>( I_C = 10 \text{ mA}, I_B = 0 )</td>
<td>800</td>
<td>—</td>
<td>—</td>
<td>V</td>
</tr>
<tr>
<td>DC current gain</td>
<td></td>
<td>( V_{CE} = 5 \text{ V}, I_C = 1 \text{ mA} )</td>
<td>10</td>
<td>—</td>
<td>—</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{CE} = 5 \text{ V}, I_C = 0.15 \text{ A} )</td>
<td>15</td>
<td>—</td>
<td>—</td>
<td>—</td>
</tr>
<tr>
<td>Collector-emitter saturation voltage</td>
<td>( V_{CE\ (sat)} )</td>
<td>( I_C = 1.2 \text{ A}, I_B = 0.24 \text{ A} )</td>
<td>—</td>
<td>—</td>
<td>1.0</td>
<td>V</td>
</tr>
<tr>
<td>Base-emitter saturation voltage</td>
<td>( V_{BE\ (sat)} )</td>
<td>( I_C = 1.2 \text{ A}, I_B = 0.24 \text{ A} )</td>
<td>—</td>
<td>—</td>
<td>1.3</td>
<td>V</td>
</tr>
</tbody>
</table>

### Switching Time

- **Rise time** \( t_r \)
  - \( V_{CC} = 360 \text{ V} \)
  - \( I_{B1} = 0.24 \text{ A}, I_{B2} = -0.48 \text{ A}, \) duty cycle \( \leq 1\% \)
  - \( 20 \mu \text{s} \)
  - Min: — | Typ.: — | Max: 0.7 | Unit: \( \mu \text{s} \)

- **Storage time** \( t_{stg} \)
  - — | Typ.: — | Max: 4.0 | Unit: \( \mu \text{s} \)

- **Fall time** \( t_f \)
  - — | Typ.: — | Max: 0.5 | Unit: \( \mu \text{s} \)

## Marking

A line indicates lead (Pb)-free package or lead (Pb)-free finish.
Collector-emitter voltage  $V_{CE}$ (V)

Collector current  $I_C$ (A)

$h_{FE}$ – $I_C$

$V_{BE}$ (sat) – $I_C$

Collector-emitter saturation voltage

Collector current  $I_C$ (A)

Base-emitter saturation voltage

Switching Characteristics

Switching time  ($\mu$s)

Common emitter

$V_{CE} = 5$ V

$T_c = 100°C$

$-55$

$25$

$25$

$-55$

$0.01$

$10$

$IC/IB = 5$

$T_c = 25°C$

$10$

$tf$

$t_{stg}$

$tr$

$IC = 5IB1$

$2IB1 = -IB2$

Pulse width = 20 µs

Duty cycle ≤ 1%

$T_c = 25°C$

$0.01$

$0.1$

$0.1$

$0.01$

$0.1$

$0.1$

$0.01$

$0.1$

$0.1$

$0.01$

$0.1$

$0.1$

$0.01$

$0.1$

$0.1$
Collector-emitter voltage $V_{CE}$ (V)

Collector current $I_C$ (A)

Ambient temperature $T_a$ (°C)

Collector power dissipation $P_C$ (W)

- Collector-emitter voltage $V_{CE}$
- Collector current $I_C$
- Ambient temperature $T_a$
- Collector power dissipation $P_C$

**Safe Operating Area**

- Single nonrepetitive pulse $T_c = 25^\circ$C
- Curves must be derated linearly with increase in temperature.

**Collector Power Dissipation**

- $P_C - T_a$
- (1) $T_c = T_a$, Infinite heat sink
- (2) No heat sink

* $T_c = 25^\circ$C

$V_{CEO}$ max

$IC_{max}$ (continuous)

$IC_{max}$ (pulsed)

Curves must be derated linearly with increase in temperature.
RESTRICTIONS ON PRODUCT USE

- The information contained herein is subject to change without notice.

- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury (“Unintended Usage”). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer’s own risk.

- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.